

# 2MBI300XBE065-50

IGBT Modules

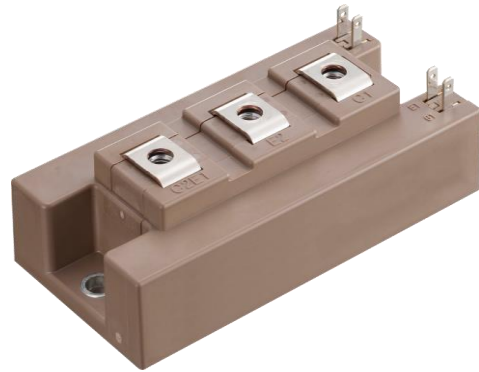
**Power Module (X series)**  
**650V / 300A / 2-in-1 package**

■ **Features**

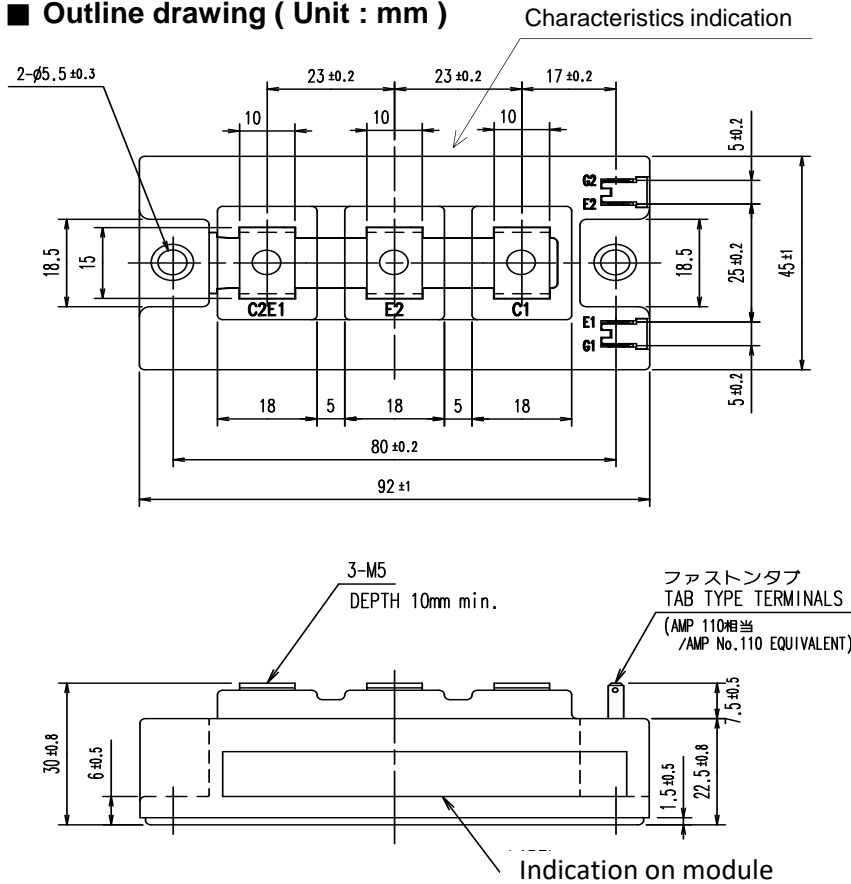
- LOW  $V_{CE(sat)}$
- High speed switching
- Low Inductance Module structure

■ **Applications**

- Inverter for Motor Drives, AC and DC Servo Drives
- Uninterruptible Power Supply Systems,
- Industrial machines, such as Welding machines

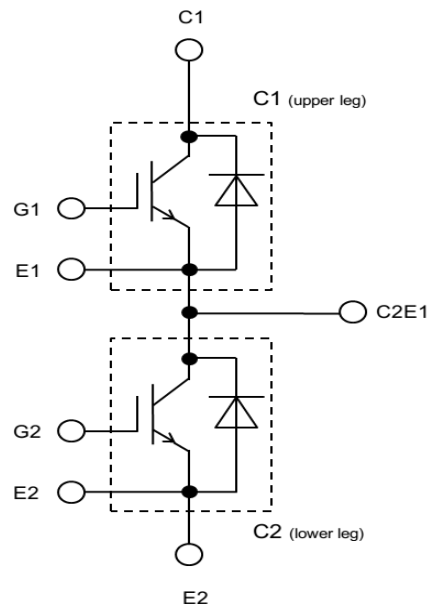


■ **Outline drawing ( Unit : mm )**



Weight: 270 g(typ.)

■ **Equivalent Circuit**





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■ Electrical characteristics (at  $T_{vj}= 25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Collector-Emitter cut-off current Gate-Emitter short-circuited	$I_{CES}$	$V_{GE} = 0V$ $V_{CE} = 650V$	-	-	100	$\mu\text{A}$	
Gate leakage current, Collector-Emitter short-circuited	$I_{GES}$	$V_{CE}=0V, V_{GE}=\pm 20V$	-	-	200	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 300\text{mA}$	6.0	6.5	7.0	V	
Collector-Emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 300A$	$T_{vj}=25^{\circ}\text{C}$	-	1.50	1.95	V
			$T_{vj}=125^{\circ}\text{C}$	-	1.30	1.75	
	$T_{vj}=150^{\circ}\text{C}$		-	1.45	-		
	$T_{vj}=175^{\circ}\text{C}$		-	1.50	-		
Internal gate	$r_g$	-	$T_{vj}=25^{\circ}\text{C}$	-	2.25	-	$\Omega$
			$T_{vj}=125^{\circ}\text{C}$	-	34	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.47	-	
			$T_{vj}=175^{\circ}\text{C}$	-	-	-	
Capacitance	$C_{ies}$	$V_{CE}=10V, V_{GE}=0V, f=1\text{MHz}$	-	1.3	-	nF	
	$C_{oes}$		-	0.47	-		
	$C_{res}$		-	-	-		
Gate charge	$Q_G$	$V_{CC} = 300V, I_C = 300A$ $V_{GE} = -15 \rightarrow +15V$	-	2.4	-	$\mu\text{C}$	
Forward voltage	$V_F$ (terminal)	$V_{GE} = 0V$ $I_F = 300A$	$T_{vj}=25^{\circ}\text{C}$	-	1.75	2.20	V
			$T_{vj}=125^{\circ}\text{C}$	-	1.55	2.00	
	$T_{vj}=150^{\circ}\text{C}$		-	1.50	-		
	$T_{vj}=175^{\circ}\text{C}$		-	1.50	-		
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 300V$ $I_C, I_F = 300A$ $V_{GE} = +15/ -15V$ $R_G = 4.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	0.37	-	$\mu\text{s}$
			$T_{vj}=125^{\circ}\text{C}$	-	0.41	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.42	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.43	-	
	$t_r$		$T_{vj}=25^{\circ}\text{C}$	-	0.12	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.14	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.14	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.15	-	
	$t_{d(off)}$		$T_{vj}=25^{\circ}\text{C}$	-	0.35	-	
			$T_{vj}=125^{\circ}\text{C}$	-	0.37	-	
			$T_{vj}=150^{\circ}\text{C}$	-	0.38	-	
			$T_{vj}=175^{\circ}\text{C}$	-	0.38	-	
$t_f$	$T_{vj}=25^{\circ}\text{C}$	-	0.07	-			
	$T_{vj}=125^{\circ}\text{C}$	-	0.09	-			
	$T_{vj}=150^{\circ}\text{C}$	-	0.10	-			
	$T_{vj}=175^{\circ}\text{C}$	-	0.10	-			
Reverse recovery time	$t_{rr}$	$T_{vj}=25^{\circ}\text{C}$	-	0.08	-		
		$T_{vj}=125^{\circ}\text{C}$	-	0.15	-		
		$T_{vj}=150^{\circ}\text{C}$	-	0.16	-		
		$T_{vj}=175^{\circ}\text{C}$	-	0.18	-		

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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■ Electrical characteristics (at  $T_{vj}=25^{\circ}\text{C}$  unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Inverter Switching loss (per pulse)	$E_{on}$	$V_{CC} = 300\text{V}$ $I_C, I_F = 300\text{A}$ $V_{GE} = +15/ -15\text{V}$ $R_G = 4.7 \Omega$ $L_S = 30 \text{ nH}$	$T_{vj}=25^{\circ}\text{C}$	-	8.9	-	mJ
			$T_{vj}=125^{\circ}\text{C}$	-	16.1	-	
			$T_{vj}=150^{\circ}\text{C}$	-	17.9	-	
			$T_{vj}=175^{\circ}\text{C}$	-	19.7	-	
	$E_{off}$		$T_{vj}=25^{\circ}\text{C}$	-	12.5	-	
			$T_{vj}=125^{\circ}\text{C}$	-	13.8	-	
			$T_{vj}=150^{\circ}\text{C}$	-	14.1	-	
			$T_{vj}=175^{\circ}\text{C}$	-	14.4	-	
	$E_{rr}$		$T_{vj}=25^{\circ}\text{C}$	-	1.5	-	
			$T_{vj}=125^{\circ}\text{C}$	-	2.5	-	
			$T_{vj}=150^{\circ}\text{C}$	-	2.8	-	
			$T_{vj}=175^{\circ}\text{C}$	-	3.1	-	

NOTICE:

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

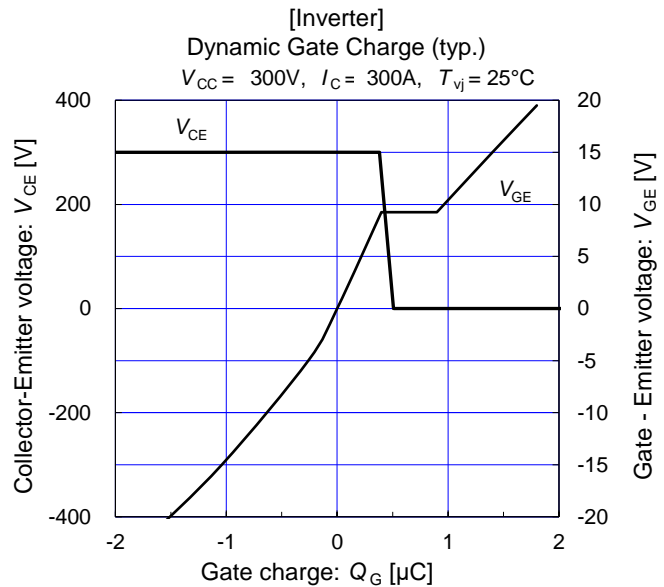
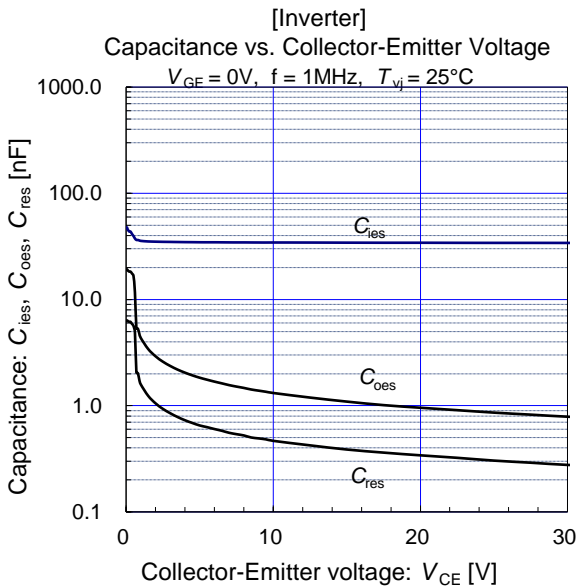
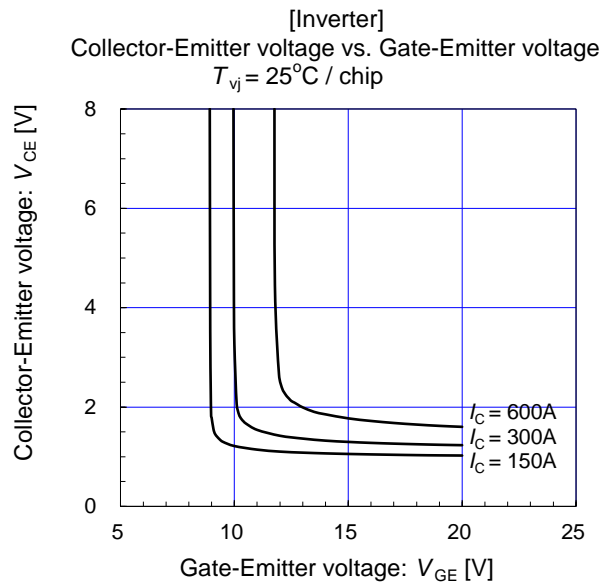
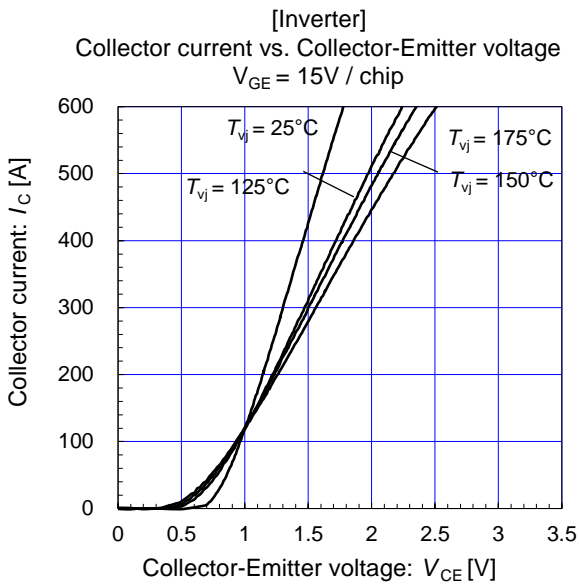
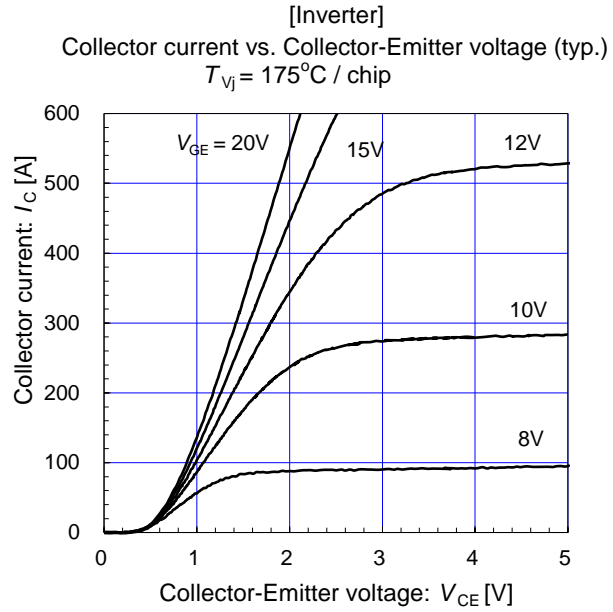
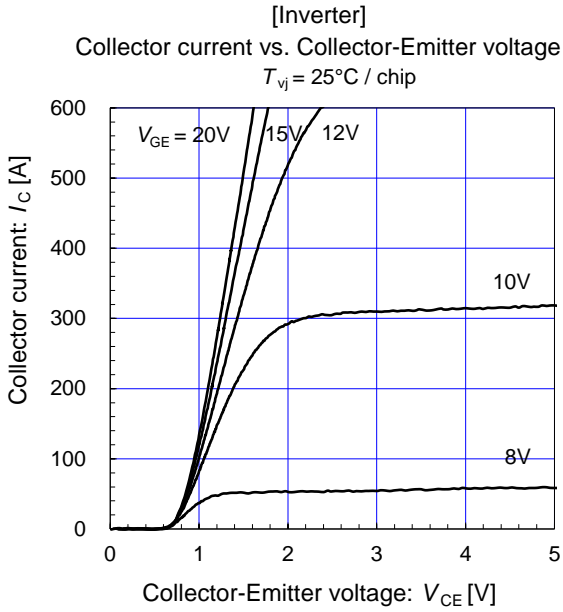
■ Thermal resistance characteristics

	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case (1device)	$R_{th(j-c)}$	Inverter IGBT	-	-	0.129	$^{\circ}\text{C/W}$
		Inverter FWD	-	-	0.174	
Thermal resistance case to heat sink (1 IGBT + 1FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal grease	-	0.0250	-	
			-	-	-	

(\*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

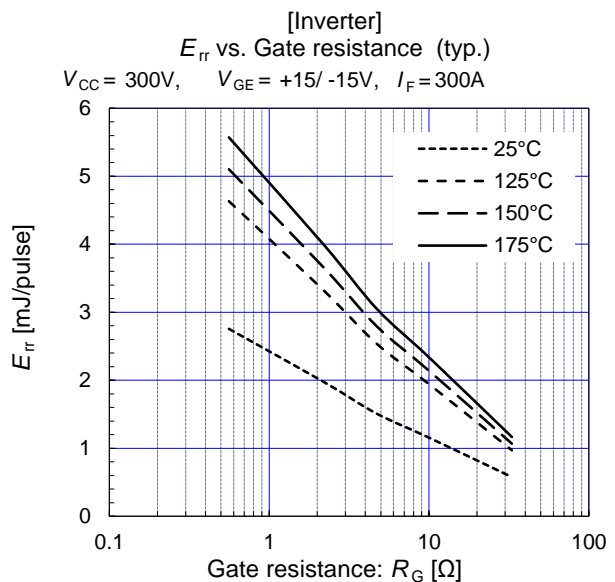
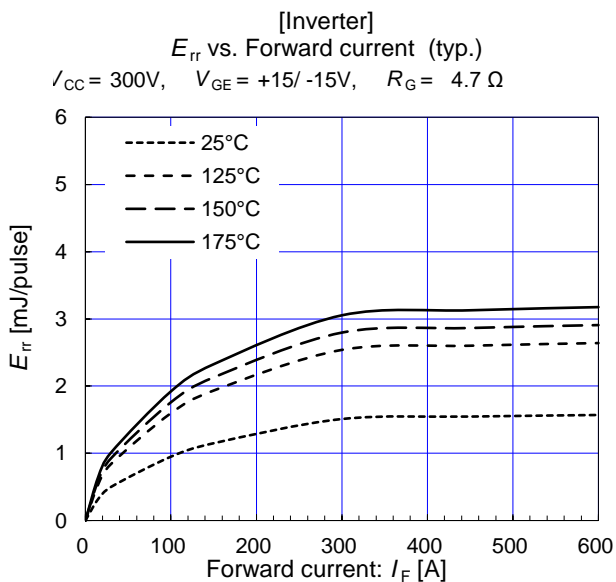
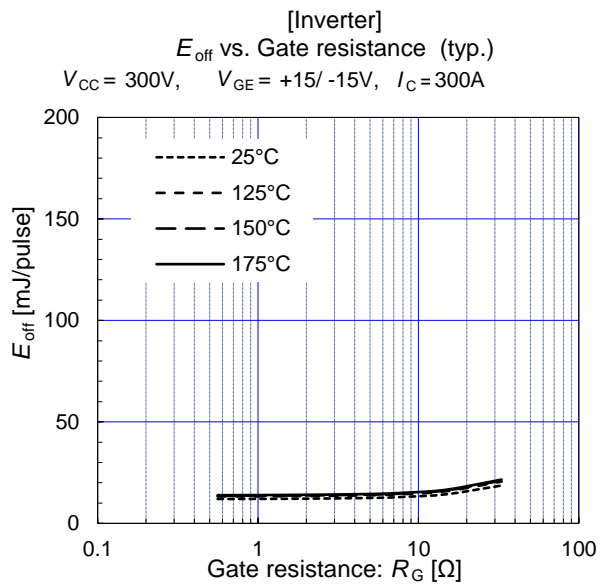
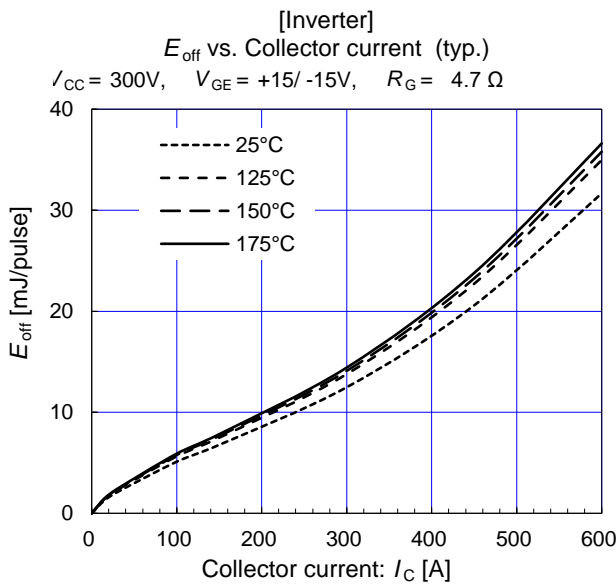
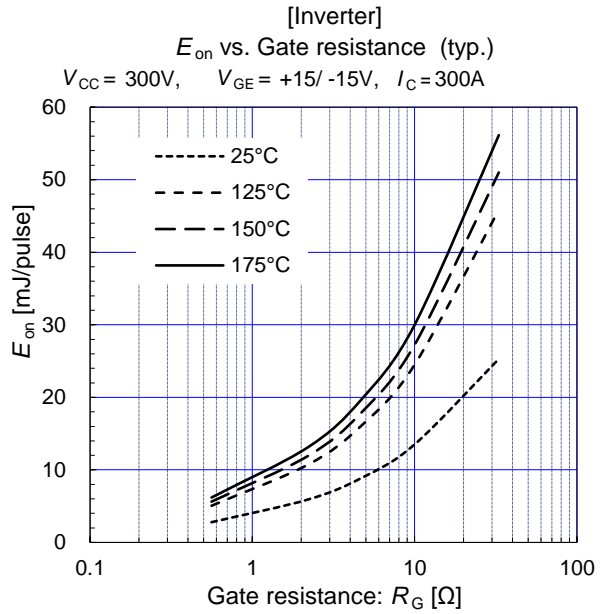
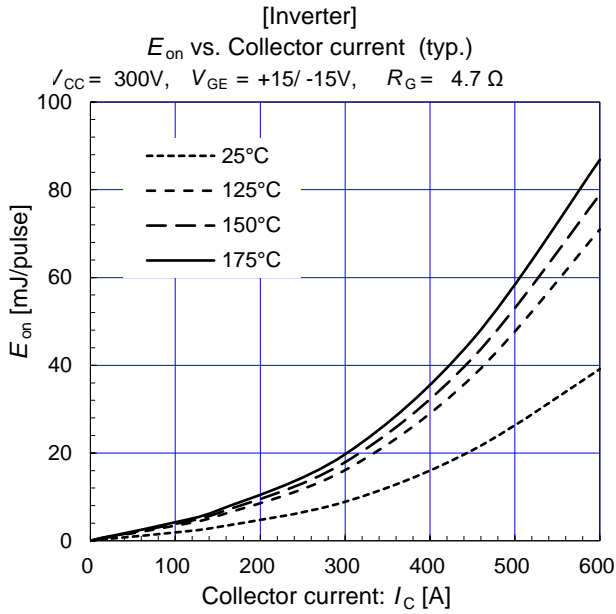
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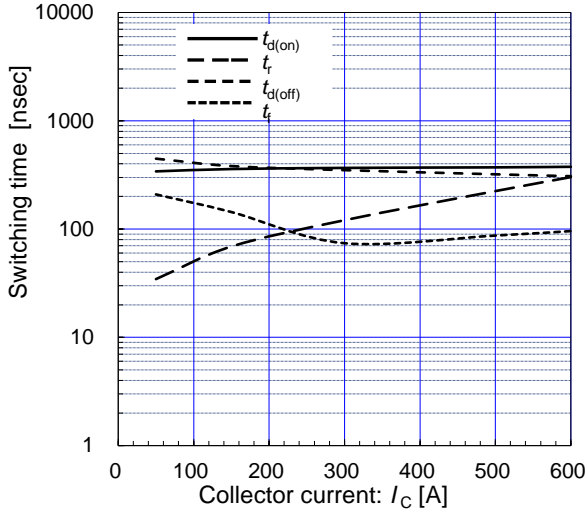
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[Inverter]

Switching time vs. Collector current (typ.)

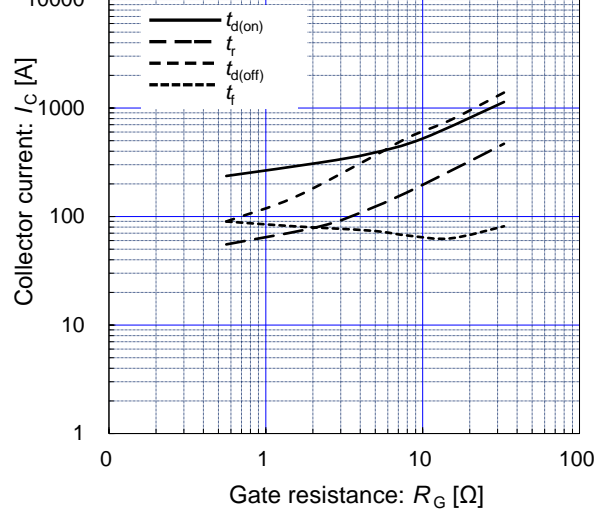
$V_{CC} = 300V, R_G = 4.7\Omega, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

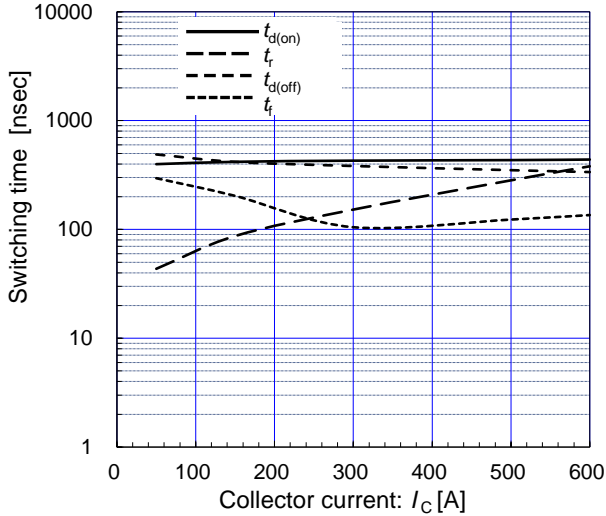
$V_{CC} = 300V, I_C = 300A, V_{GE} = +15/-15V, T_{vj} = 25^\circ C$



[Inverter]

Switching time vs. Collector current (typ.)

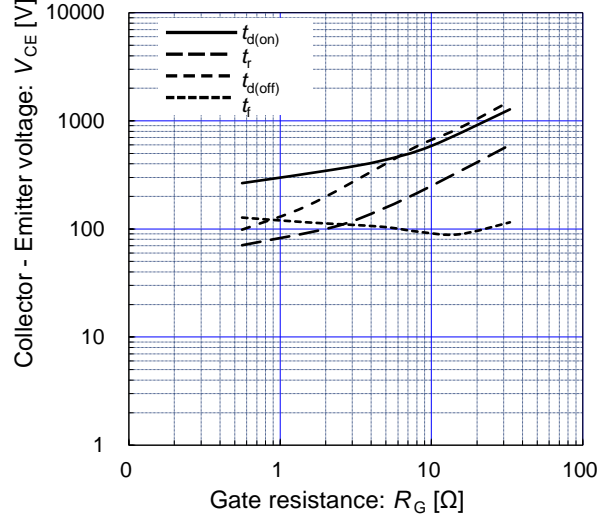
$V_{CC} = 300V, R_G = 4.7\Omega, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

Switching time vs. Gate resistance (typ.)

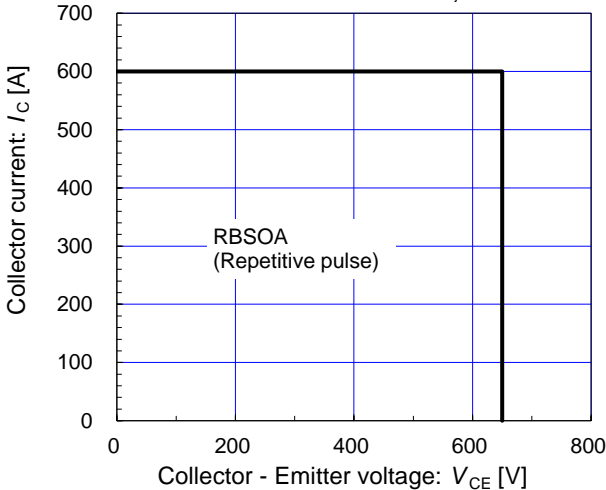
$V_{CC} = 300V, I_C = 300A, V_{GE} = +15/-15V, T_{vj} = 175^\circ C$



[Inverter]

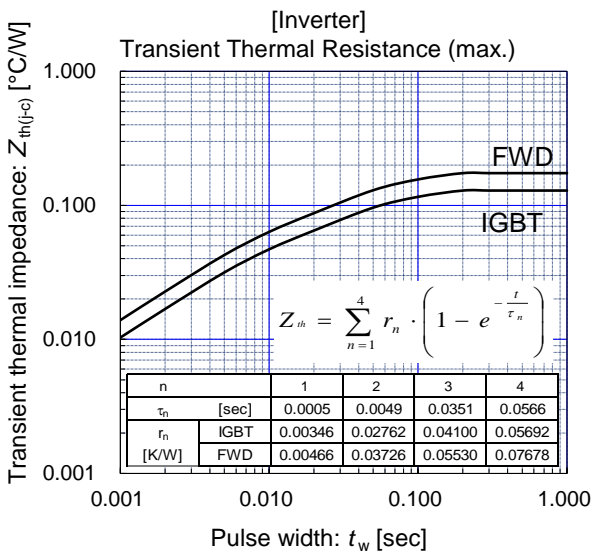
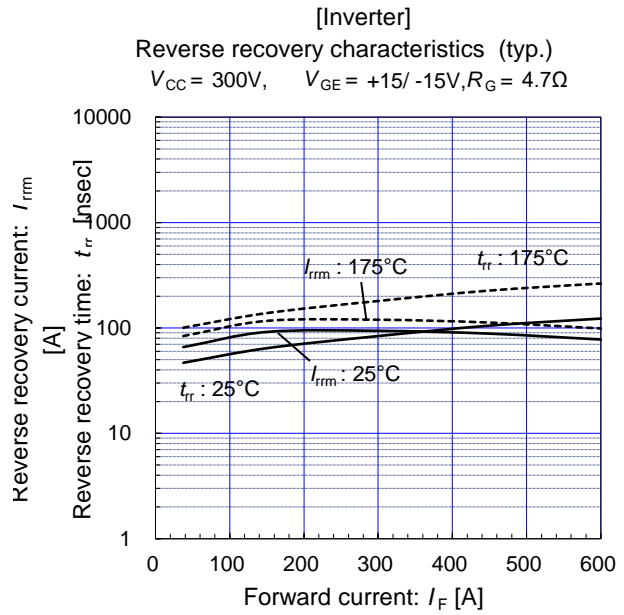
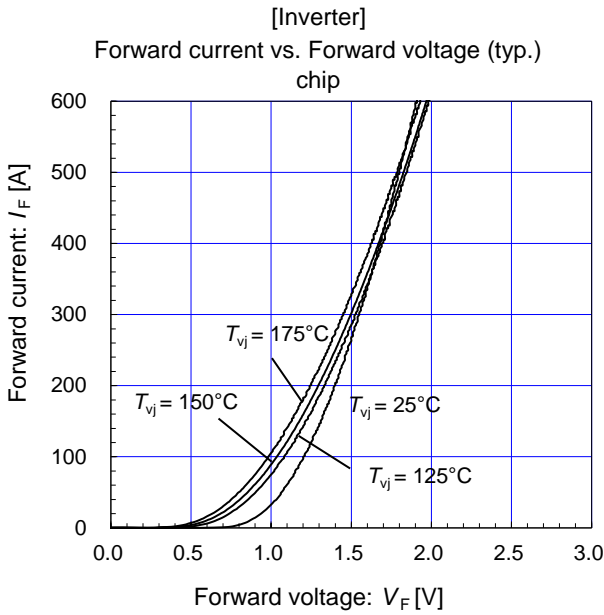
Reverse bias safe operating area (max.)

$V_{GE} = +15/-15V, R_G = 4.7\Omega, T_{vj} = 175^\circ C$



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